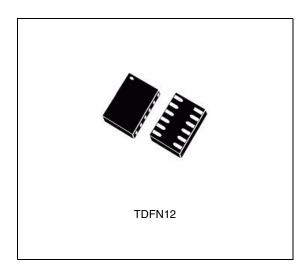


STM6600 STM6601

Smart push-button on/off controller with Smart Reset[™] and power-on lockout

Features

- Operating voltage 1.6 V to 5.5 V
- Low standby current of 0.6 µA
- Adjustable Smart Reset[™] assertion delay time driven by external C_{SRD}
- Power-up duration determined primarily by push-button press (STM6600) or by fixed time period, t_{ON_BLANK} (STM6601)
- Debounced PB and SR inputs
- PB and SR ESD inputs withstand voltage up to ±15 kV (air discharge) ±8 kV (contact discharge)
- Active high or active low enable output option (EN or EN) provides control of MOSFET, DC-DC converter, regulator, etc.
- Secure startup, interrupt, Smart Reset[™] or power-down driven by push-button
- Precise 1.5 V voltage reference with 1% accuracy
- Industrial operating temperature -40 to +85 °C
- Available in TDFN12 2 x 3 mm package



Applications

- Portable devices
- Terminals
- Audio and video players
- Cell phones and smart phones
- PDAs, palmtops, organizers

Table 1.	Device	summarv
----------	--------	---------

Device	RST	C _{SRD}	PB/SR	EN or EN	ĪNT	Startup process
STM6600	open drain ⁽¹⁾	>	1	push-pull	open drain ⁽¹⁾	PB must be held low until the PS _{HOLD} ⁽²⁾ confirmation
STM6601	open drain ⁽¹⁾	1	/	push-pull	open drain ⁽¹⁾	PB can be released before the PS _{HOLD} ⁽²⁾ confirmation

^{1.} External pull-up resistor needs to be connected to open drain outputs.

2. For a successful startup, the PS_{HOLD} (Power Supply Hold) needs to be pulled high within specific time, t_{ON_BLANK}.

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STM6600 - STM6601 Description

1 Description

The STM6600-01 devices monitor the state of connected push-button(s) as well as sufficient supply voltage. An enable output controls power for the application through the MOSFET transistor, DC-DC converter, regulator, etc. If the supply voltage is above a precise voltage threshold, the enable output can be asserted by a simple press of the button. Factory-selectable supply voltage thresholds are determined by highly accurate and temperature-compensated references. An interrupt is asserted by pressing the push-button during normal operation and can be used to request a system power-down. The interrupt is also asserted if undervoltage is detected. By a long push of one button (\overline{PB}) or two buttons (\overline{PB}) and (\overline{SR}) either a reset is asserted or power for the application is disabled depending on the option used.

The device also offers additional features such as precise 1.5 V voltage reference with very tight accuracy of 1%, separate output indicating undervoltage detection and separate output for distinguishing between interrupt by push-button or undervoltage.

The device consumes very low current of 6 μA during normal operation and only 0.6 μA current during standby.

The STM6600-01 is available in the TDFN12 package and is offered in several options among features such as selectable threshold, hysteresis, timeouts, output types, etc. (see *Table 8* and *Table 9* for more information).

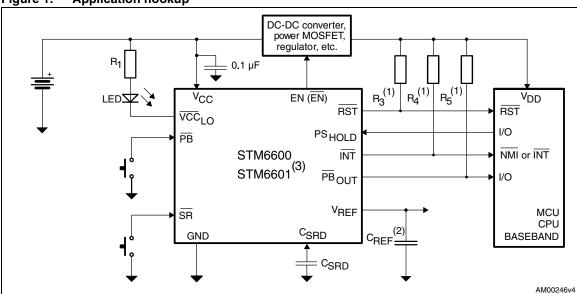


Figure 1. Application hookup

- 1. A resistor is required for open drain output type only. A 10 k Ω pull-up is sufficient in most applications.
- 2. Capacitor C_{REF} is mandatory on V_{REF} output (even if V_{REF} is not used). Capacitor value of 1 μ F is recommended.
- 3. For the STM6601 the processor has to confirm the proper power-on during the fixed time period, t_{ON_BLANK}. This failsafe feature prevents the user from turning on the system when there is a faulty power switch or an unresponsive microprocessor.



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Description STM6600 - STM6601

POWER-UP⁽¹⁾ INTERRUPT (short push) (long push)

EN

INT

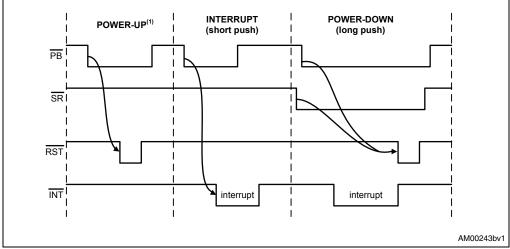
interrupt interrupt

AM00243v1

Figure 2. Basic functionality (option with enable deassertion after long push)

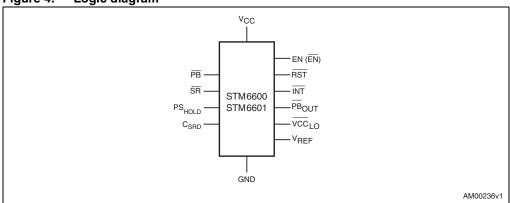
1. For power-up the battery voltage has to be above V_{TH+} threshold.

Figure 3. Basic functionality (option with RST assertion after long push)



1. For power-up the battery voltage has to be above $\ensuremath{V_{TH_+}}$ threshold.

Figure 4. Logic diagram



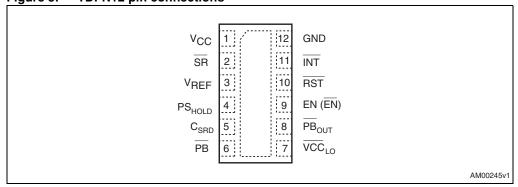
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STM6600 - STM6601 Description

Table 2. Pin descriptions

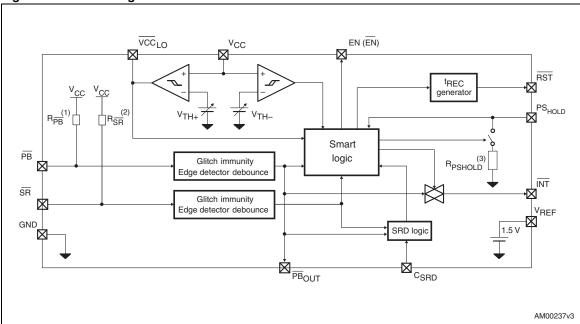
Pin number	Symbol	Function
1	V_{CC}	Power supply input
2	SR	Smart Reset [™] button input
3	V_{REF}	Precise 1.5 V voltage reference
4	PS _{HOLD}	PS _{HOLD} input
5	C _{SRD}	Adjustable Smart Reset [™] delay time input
6	PB	Push-button input
7	VCC _{LO}	Output for high threshold comparator output (V _{TH+})
8	PB _{OUT}	Status of PB push-button input
9	EN or EN	Enable output
10	RST	Reset output
11	ĪNT	Interrupt output
12	GND	Ground

Figure 5. TDFN12 pin connections



Description STM6600 - STM6601

Figure 6. Block diagram



- 1. Internal pull-up resistor connected to \overline{PB} input (see *Table 5* for precise specifications).
- 2. Optional internal pull-up resistor connected to \$\overline{SR}\$ input (see Table 5 for precise specifications and Table 10 for detailed device options).
- 3. Internal pull-down resistor is connected to PS_{HOLD} input only during startup (see Figure 7, 8, 9, 10, 11, 12, 13, and 18).

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STM6600 - STM6601 Pin descriptions

2 Pin descriptions

V_{CC} - power supply input

 $V_{\rm CC}$ is monitored during startup and normal operation for sufficient voltage level. Decouple the $V_{\rm CC}$ pin from ground by placing a 0.1 μ F capacitor as close to the device as possible.

SR - Smart Reset[™] button input

This input is equipped with voltage detector with a factory-trimmed threshold and has ± 8 kV HBM ESD protection.

Both \overline{PB} and \overline{SR} buttons have to be pressed and held for t_{SRD} period so the long push is recognized and the reset is asserted (or the enable output is deasserted depending on the option) - see *Figure 15*, *16*, and *17*.

Active low \overline{SR} input is usually connected to GND through the momentary push-button (see *Figure 1*) and it has an optional 100 k Ω pull-up resistor. It is also possible to drive this input using an external device with either open drain (recommended) or push-pull output. Open drain output can be connected in parallel with push-button or other open drain outputs, which is not possible with push-pull output.

V_{REF} - external precise 1.5 V voltage reference

This 1.5 V voltage reference is specified with very tight accuracy of 1% (see *Table 5*). It has proper output voltage as soon as the reset output is deasserted (i.e. after t_{REC} expires) and it is disabled when the device enters standby mode. A mandatory capacitor needs to be connected to V_{REF} output (even if V_{REF} is not used). Capacitor value of 1 μF is recommended.

PS_{HOLD} input

This input is equipped with a voltage detector with a factory-trimmed threshold. It is used to confirm correct power-up of the device (if EN or $\overline{\text{EN}}$ is not asserted) or to initiate a shutdown (if EN or $\overline{\text{EN}}$ is asserted).

Forcing PS_{HOLD} high during power-up confirms the proper start of the application and keeps enable output asserted. Because most processors have outputs in high-Z state before initialization, an internal pull-down resistor is connected to PS_{HOLD} input during startup (see *Figure 7, 8, 9, 10, 11, 12, 13*, and *18*).

Forcing the PS_{HOLD} signal low during normal operation deasserts the enable output (see *Figure 14*). Input voltage on this pin is compared to an accurate voltage reference.

C_{SRD} - Smart Reset[™] delay time input

A capacitor to ground determines the additional time (t_{SRD}) that \overline{PB} with \overline{SR} must be pressed and held before a long push is recognized. The connected C_{SRD} capacitor is charged with I_{SRD} current. Additional Smart Reset delay time t_{SRD} ends when voltage on the C_{SRD} capacitor reaches the V_{SRD} voltage threshold. It is recommended to use a low ESR capacitor (e.g. ceramic). If the capacitor is not used, leave the C_{SRD} pin open. If no capacitor is connected, there is no t_{SRD} and a long push is recognized right after $t_{\overline{INT}_Min}$ expires (see *Figure 18* and *19*).



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Pin descriptions STM6600 - STM6601

PB - power ON switch

This input is equipped with a voltage detector with a factory-trimmed threshold and has \pm 8 kV HBM ESD protection.

When the \overline{PB} button is pressed and held, the battery voltage is detected and EN (or \overline{EN}) is asserted if the battery voltage is above the threshold V_{TH+} during the whole $t_{DEBOUNCE}$ period (see *Figure 13*).

A short push of the push-button during normal operation can initiate an interrupt through debounced $\overline{\text{INT}}$ output (see *Figure 14*) and a long push of $\overline{\text{PB}}$ and $\overline{\text{SR}}$ simultaneously can either assert reset output $\overline{\text{RST}}$ (see *Figure 18*) or deassert the EN or $\overline{\text{EN}}$ output (see *Figure 19*) based on the option used.

Note:

A switch to GND must be connected to this input (e.g. mechanical push-button, open drain output of external circuitry, etc.), see Figure 1. This ensures a proper startup signal on \overline{PB} (i.e. a transition from full V_{CC} below specified V_{IL}). \overline{PB} input has an internal 100 k Ω pull-up resistor connected.

VCC_{LO} - high threshold detection output

During power-up, \overline{VCC}_{LO} is low when V_{CC} supply voltage is below the V_{TH+} threshold. After successful power-up (i.e. during normal operation) \overline{VCC}_{LO} is low anytime undervoltage is detected (see *Figure 13*).

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 $k\Omega$ is sufficient in most applications.

VCC_{I O} is floating when STM660x is in standby mode.

PB_{OUT} - PB input state

If the push-button \overline{PB} is pressed, the pin stays low during the $t_{DEBOUNCE}$ time period. If \overline{PB} is asserted for the entire $t_{DEBOUNCE}$ period, \overline{PB}_{OUT} will then stay low for at least $t_{\overline{INT}_Min}$. If \overline{PB} is asserted after $t_{\overline{INT}_Min}$ expires, \overline{PB}_{OUT} will return high as soon as \overline{PB} is deasserted (see Figure~22). \overline{PB}_{OUT} ignores \overline{PB} assertion during an undervoltage condition. At startup on the STM6601 \overline{PB}_{OUT} will respond only to the first \overline{PB} assertion and any other assertion will be ignored until t_{ON_BLANK} expires. This output is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.



STM6600 - STM6601 Pin descriptions

EN or EN - enable output

This output is intended to enable system power (see *Figure 1*). EN is asserted **high** after a valid turn-on event has been detected and confirmed (i.e. push-button has been pressed and held for $t_{DEBOUNCE}$ or more and $V_{CC} > V_{TH+}$ voltage level has been detected - see *Figure 13*). EN is released **low** if any of the conditions below occur:

- a) the push-button is released before PS_{HOLD} is driven high (valid for STM6600, see Figure 9) or t_{ON_BLANK} expires before PS_{HOLD} is driven high during startup (valid for both STM6600 and STM6601, see Figure 10 and 12).
- b) PS_{HOLD} is driven low during normal operation (see *Figure 14*).
- c) an undervoltage condition is detected for more than $t_{SRD} + t_{\overline{INT}_Min} + t_{DEBOUNCE}$ (see *Figure 21*).
- d) a long push of the buttons is detected (only for the device with option "EN deasserted by long push" see *Figure 19*) or PS_{HOLD} is not driven high during t_{ON_BLANK} after a long push of the buttons (only for the device with option "RST asserted by long push" see *Figure 18*).

Described logic levels are inverted in case of EN output. Output type is push-pull by default.

RST - reset output

This output pulls low for t_{REC}:

- a) during startup. \overline{PB} has been pressed (falling edge on the \overline{PB} detected) and held for at least t_{DEBOUNCE} and V_{CC} > V_{TH+} (see *Figure 7, 8, 9, 10, 11, 12* and *13* for more details).
- b) after long push detection (valid only for the device with option "RST asserted by long push"). PB has been pressed (falling edge on the PB detected) and held for more than t_{DEBOUNCE} + t_{SRD} (additional Smart Reset[™] delay time can be adjusted by the external capacitor C_{SRD}) see *Figure 18*.

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 $k\Omega$ is sufficient in most applications.

INT - interrupt output

While the system is under normal operation (PS_{HOLD} is driven high, power for application is asserted), the \overline{INT} is driven **low** if:

- a) V_{CC} falls below V_{TH-} threshold (i.e. undervoltage is detected see *Figure 20* and 21).
- b) the falling edge on the \overline{PB} is detected and the push-button is held for $t_{DEBOUNCE}$ or more. \overline{INT} is driven low after $t_{DEBOUNCE}$ and stays low as long as \overline{PB} is held. The \overline{INT} signal is held high during power-up.

The state of the \overline{PB}_{OUT} output can be used to determine if the interrupt was caused by either the assertion of the \overline{PB} input, or was due to the detection of an undervoltage condition on V_{CC} .

INT output is asserted low for at least tint Min.

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 $k\Omega$ is sufficient in most applications.

GND - ground



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Operation STM6600 - STM6601

Operation 3

The STM6600-STM6601 simplified smart push-button on/off controller with Smart Reset™ and power-on lockout enables and disables power for the application depending on pushbutton states, signals from the processor, and battery voltage.

Power-on

Because most of the processors have outputs in high-Z state before initialization, an internal pull-down resistor is connected to PS_{HOLD} input during startup (see Figure 7, 8, 9, 10, 11,

To power up the device the push-button PB has to be pressed for at least to Describe and V_{CC} has to be above V_{TH+} for the whole $t_{DEBOUNCE}$ period. If the battery voltage drops below V_{TH+} during the $t_{DEBOUNCE}$, the counter is reset and starts to count again when V_{CC} > V_{TH+} (see Figure 13). After $t_{DEBOUNCE}$ the enable signal is asserted (EN goes high, \overline{EN} goes low), reset output $\overline{\text{RST}}$ is asserted for t_{REC} and then the startup routine is performed by the processor. During initialization, the processor sets the PS_{HOLD} signal high.

On the STM6600 the PS_{HOLD} signal has to be set high prior to push-button release and ton BLANK expiration, otherwise the enable signal is deasserted (EN goes low, EN goes high) - see Figure 7, 8, 9, and 10. The time up to push-button release represents the maximum time allowed for the system to power up and initialize the circuits driving the PS_{HOLD} input. If the PS_{HOLD} signal is low at push-button release, the enable output is deasserted immediately, thus turning off the system power. If ton BLANK expires prior to push-button release, the PS_{HOLD} state is checked at its expiration. This safety feature disables the power and prevents discharging the battery if the push-button is stuck or it is held for an unreasonable period of time and the application is not responding (see *Figure 8* and 10). PB status, INT status and V_{CC} undervoltage detection are not monitored until power-up is completed.

On the STM6601 the PS_{HOLD} signal has to be set high before t_{ON-BLANK} expires, otherwise the enable signal is deasserted - see Figure 11 and 12. In this case the ton BLANK period is the maximum time allowed for the power switch and processor to perform the proper poweron. If the PS_{HOLD} signal is low at the end of the blanking period, the enable output is released immediately, thus turning off the system power. PB status, INT status and V_{CC} undervoltage detection are not monitored during the entire ton BLANK period. This failsafe feature prevents the user from turning on the system when there is a faulty power switch or an unresponsive microprocessor.

Push-button interrupt

If the device works under normal operation (i.e. PS_{HOLD} is high) and the push-button \overline{PB} is pressed for more than t_{DEBOUNCE}, a negative pulse with minimum t_{INT_Min} width is generated on the INT output. By connecting INT to the processor interrupt input (INT or NMI) a safeguard routine can be performed and the power can be shut down by setting PS_{HOLD} low - see Figure 14.

Forced power-down mode

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The PS_{HOLD} output can be forced low anytime during normal operation by the processor and can deassert the enable signal - see Figure 14.

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Undervoltage detection

If V_{CC} voltage drops below V_{TH} voltage threshold during normal operation, the \overline{INT} output is driven low (see *Figure 20* and *Figure 21*).

If an undervoltage condition is detected for $t_{DEBOUNCE} + t_{\overline{INT}_Min} + t_{SRD}$, the enable output is deasserted (see *Figure 21*).

Hardware reset or power-down while system not responding

If the system is not responding and the system hangs, the \overline{PB} and \overline{SR} push-buttons can be pressed simultaneously longer than $t_{DEBOUNCE} + t_{\overline{INT}_Min} + t_{SRD}$, and then

- a) either the reset output $\overline{\mathsf{RST}}$ is asserted for $\mathsf{t}_{\mathsf{REC}}$ and the processor is reset (valid only for the device with option " $\overline{\mathsf{RST}}$ asserted by long push") see *Figure 18*
- b) or the power is disabled by EN or $\overline{\text{EN}}$ signal (valid only for the device with option "EN deasserted by long push") see *Figure 19*

The t_{SRD} is set by the external capacitor connected to the C_{SRD} pin.

Standby

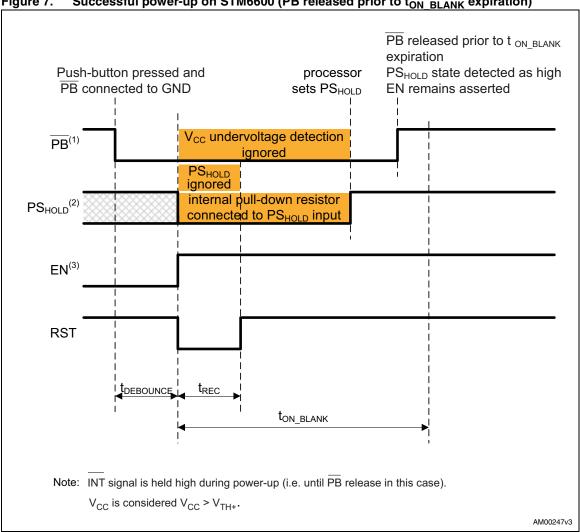
If the enable output is deasserted (i.e. EN is low or $\overline{\text{EN}}$ is high), the STM660x device enters standby mode with low current consumption (see *Table 5*). In standby mode $\overline{\text{PB}}$ input is only monitored for the falling edge. The external 1.5 V voltage reference is also disabled in standby mode.

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Waveforms STM6600 - STM6601

Waveforms 4





- 1. PB detection on falling and rising edges.
- 2. Internal pull-down resistor 300 $k\Omega$ is connected to PS_{HOLD} input during power-up.
- 3. EN signal is high even after \overline{PB} release, because processor sets PS_{HOLD} signal high before \overline{PB} is released.

STM6600 - STM6601 **Waveforms**

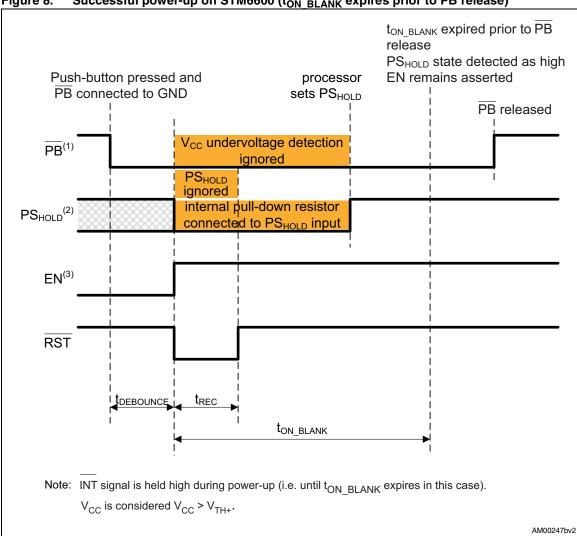
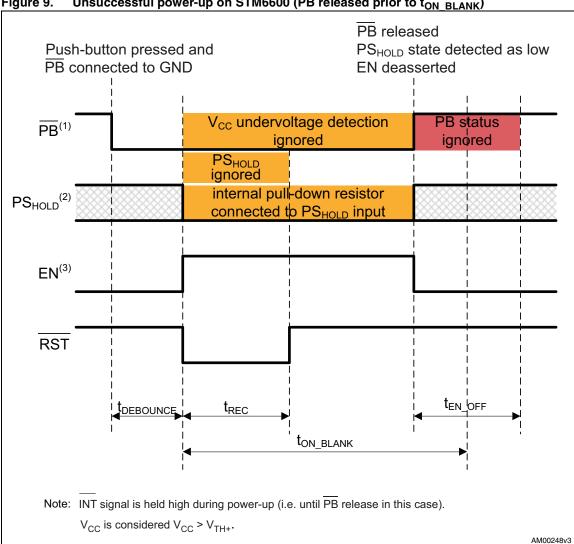


Figure 8. Successful power-up on STM6600 (ton_Blank expires prior to PB release)

- 1. \overline{PB} detection on falling and rising edges.
- 2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
- 3. t_{ON_BLANK} expires prior to \overline{PB} release so PS_{HOLD} is checked at its expiration.

Waveforms STM6600 - STM6601



Unsuccessful power-up on STM6600 (PB released prior to ton BLANK) Figure 9.

- 1. PB detection on falling and rising edges.
- 2. Internal pull-down resistor 300 $k\Omega$ is connected to PS_{HOLD} input during power-up.
- 3. EN signal goes low with \overline{PB} release, because processor did not force PS_{HOLD} signal high.

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STM6600 - STM6601 Waveforms

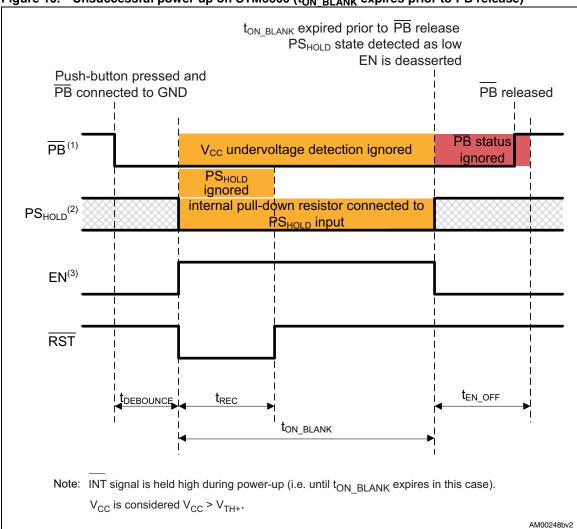
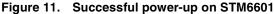
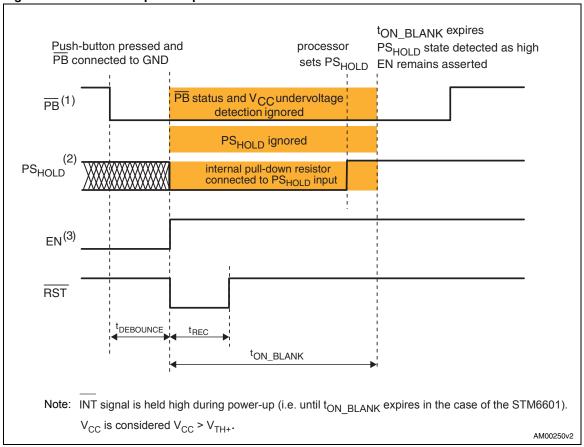


Figure 10. Unsuccessful power-up on STM6600 (t_{ON_BLANK} expires prior to PB release)

- 1. \overline{PB} detection on falling and rising edges.
- 2. Internal pull-down resistor 300 $k\Omega$ is connected to PS_{HOLD} input during power-up.
- 3. t_{ON_BLANK} expires prior to \overline{PB} release so PS_{HOLD} is checked at its expiration.

Waveforms STM6600 - STM6601



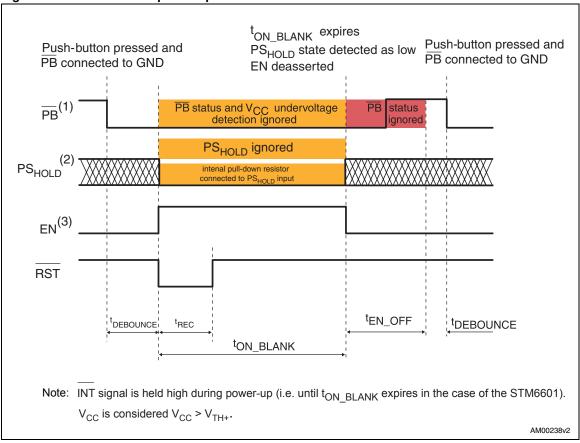


- 1. PB detection on falling edge.
- 2. Internal pull-down resistor 300 $k\Omega$ is connected to PS_{HOLD} input during power-up.
- PS_{HOLD} signal is ignored during t_{ON_BLANK}. When t_{ON_BLANK} expires, the level of the PS_{HOLD} signal is high therefore the EN signal remains asserted.

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STM6600 - STM6601 Waveforms

Figure 12. Unsuccessful power-up on STM6601



- 1. PB detection on falling edge.
- 2. Internal pull-down resistor 300 $k\Omega$ is connected to PS_{HOLD} input during power-up.
- 3. PS_{HOLD} signal is ignored during t_{ON_BLANK} . When t_{ON_BLANK} expires, the level of the PS_{HOLD} signal is not high therefore the EN signal goes low. Even releasing the \overline{PB} button after the t_{ON_BLANK} will not prevent this.

Waveforms STM6600 - STM6601

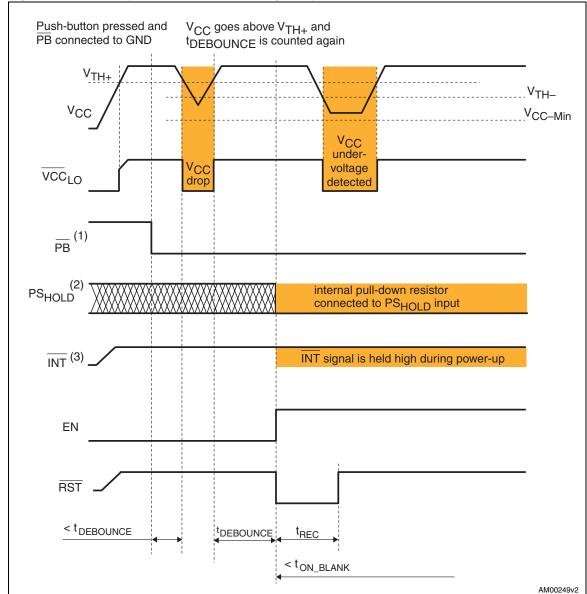


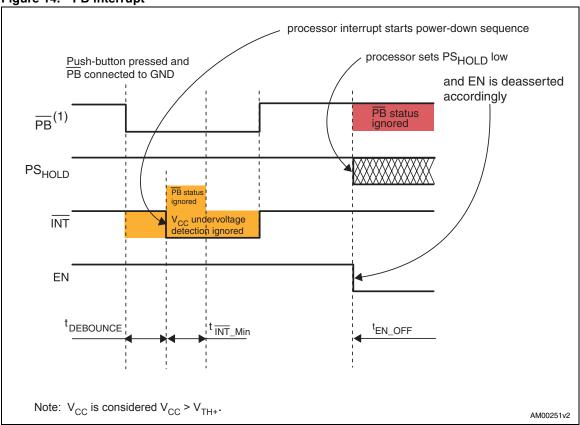
Figure 13. Power-up on STM660x with voltage dropout

- 1. \overline{PB} detection on falling and rising edges.
- 2. Internal pull-down resistor 300 $k\Omega$ is connected to PS_{HOLD} input during power-up.
- 3. $\overline{\text{INT}}$ signal is held high during power-up.

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STM6600 - STM6601 Waveforms

Figure 14. PB interrupt



1. PB detection on falling edge.

Waveforms STM6600 - STM6601

Figure 15. Long push, PB pressed first

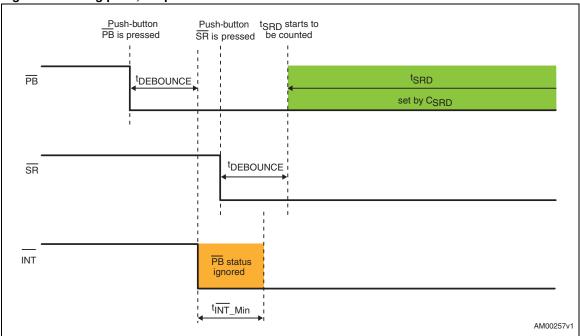
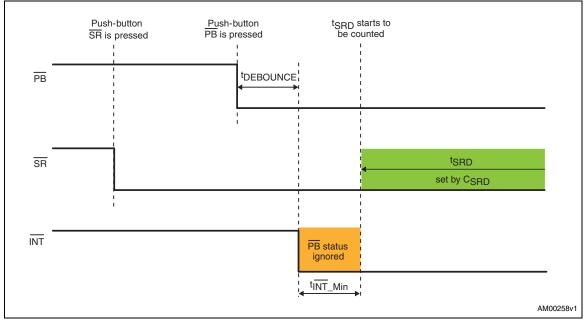


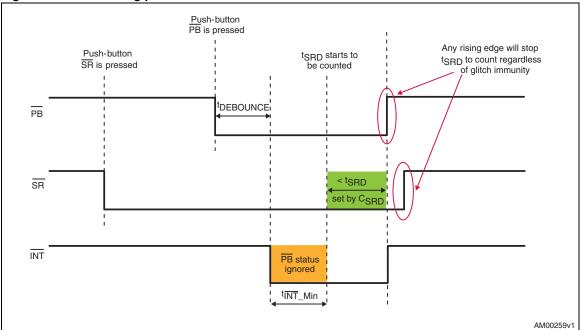
Figure 16. Long push, $\overline{\text{SR}}$ pressed first



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Figure 17. Invalid long push



Waveforms STM6600 - STM6601

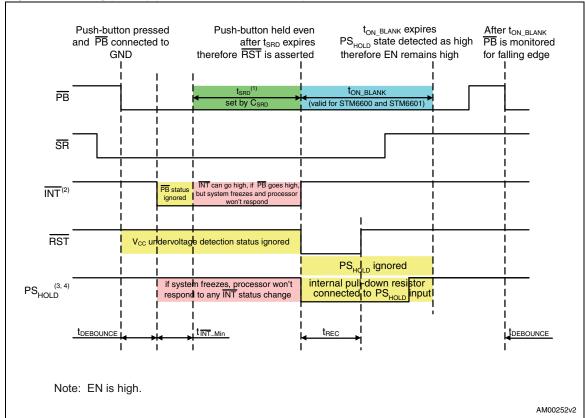


Figure 18. Long push (option with RST assertion)

- 1. t_{SRD} period is set by external capacitor C_{SRD} .
- 2. \overline{PB} ignored during $t_{\overline{INT}_Min}.$
- PS_{HOLD} signal is ignored during t_{ON_BLANK}. Its level is checked after t_{ON_BLANK} expires and if it is high the EN signal remains asserted, otherwise EN goes low.
- 4. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during startup when device is reset.

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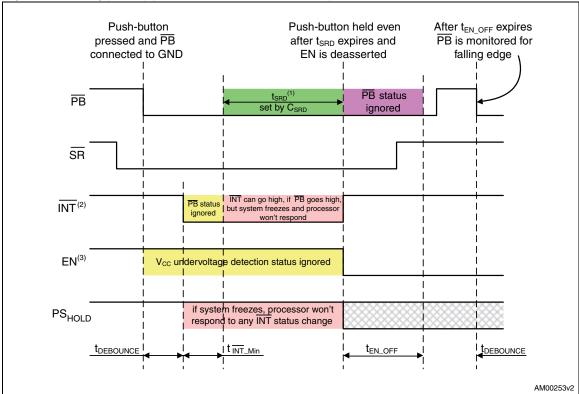
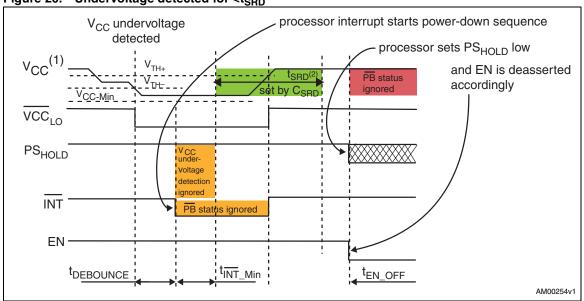


Figure 19. Long push (option with enable deassertion)

- 1. t_{SRD} period is set by external capacitor C_{SRD} .
- 2. \overline{PB} ignored during $t_{\overline{INT}_Min}$.
- 3. After t_{SRD} expires EN is forced low.

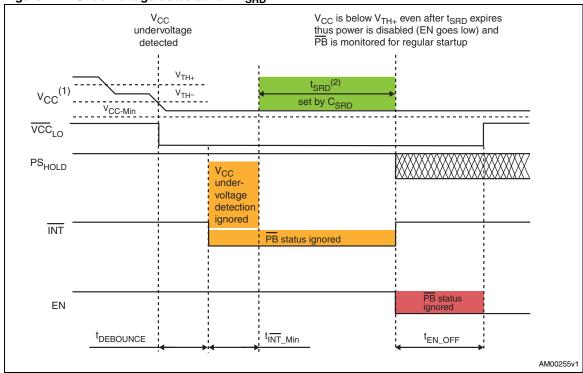
Waveforms STM6600 - STM6601

Figure 20. Undervoltage detected for <t SRD



- 1. V_{CC} goes above V_{TH+} within t_{SRD} thus power is not disabled after t_{SRD} expires.
- 2. t_{SRD} period is set by external capacitor C_{SRD} .

Figure 21. Undervoltage detected for >t_{SRD}

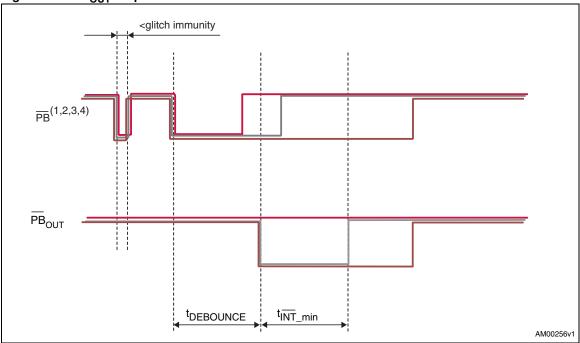


- 1. After t_{SRD} expires V_{CC} is still insufficient (below V_{TH+}) thus power is disabled (EN goes low or \overline{EN} goes high).
- 2. t_{SRD} period is set by external capacitor C_{SRD}.

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- 1. Pulses on \overline{PB} shorter than glitch immunity are ignored.
- 2. Pulses on \overline{PB} shorter than $t_{DEBOUNCE}$ are not recognized by \overline{PB}_{OUT} .
- 3. Minimum pulse width on \overline{PB}_{OUT} is $t_{\overline{INT}_{Min}}$.
- 4. If push-button is held longer than $t_{DEBOUNCE} + t_{\overline{INT}_Min}$, \overline{PB}_{OUT} goes high when the push-button is released.

5 Typical operating characteristics

Figure 23. Supply current vs. temperature, normal state

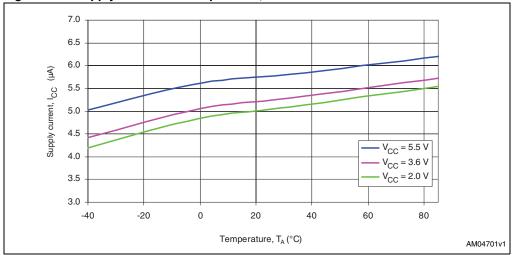
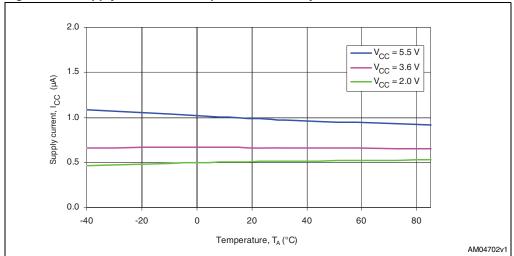


Figure 24. Supply current vs. temperature, standby state



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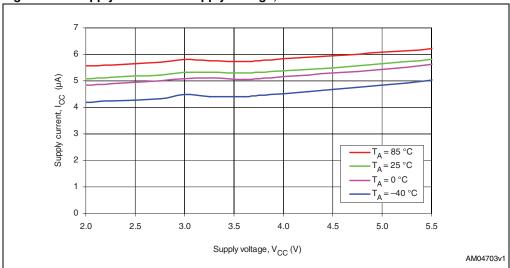
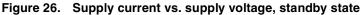
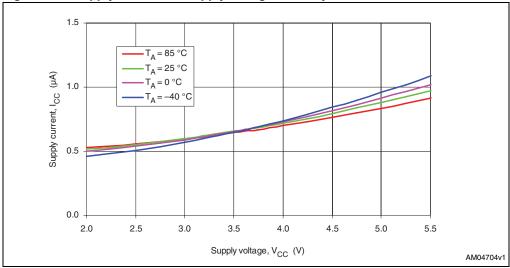


Figure 25. Supply current vs. supply voltage, normal state





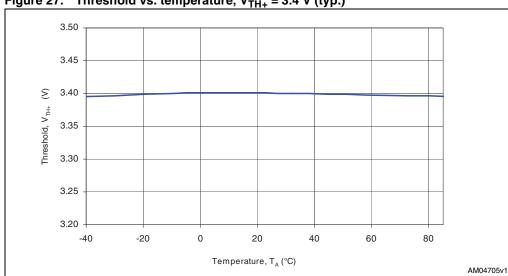
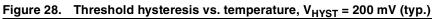
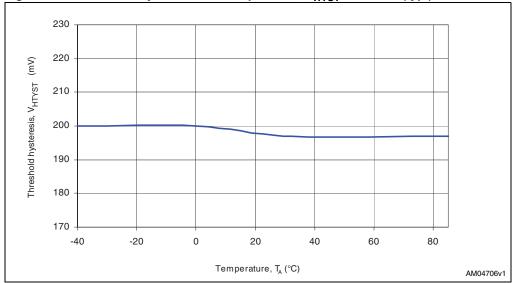


Figure 27. Threshold vs. temperature, $V_{TH+} = 3.4 \text{ V (typ.)}$





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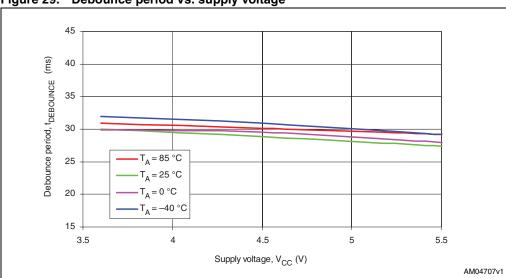
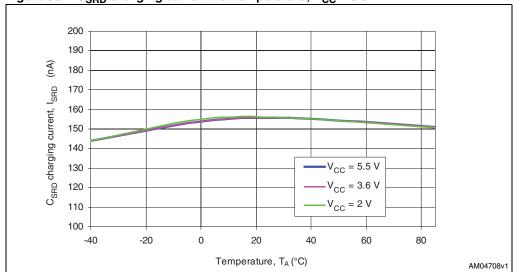


Figure 29. Debounce period vs. supply voltage





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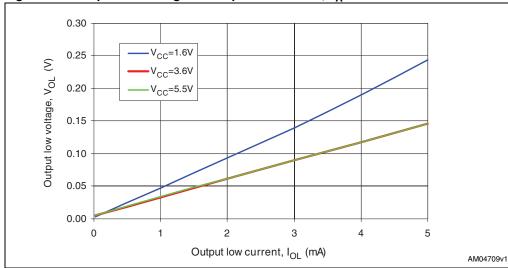
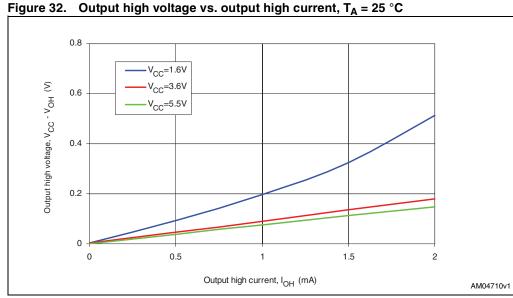


Figure 31. Output low voltage vs. output low current, $T_A = 25$ °C

Characteristics valid for all the outputs (EN, \overline{EN} , \overline{RST} , \overline{INT} , \overline{PB}_{OUT} and \overline{VCC}_{LO}). Note:



Note: Characteristics valid for EN and EN outputs.

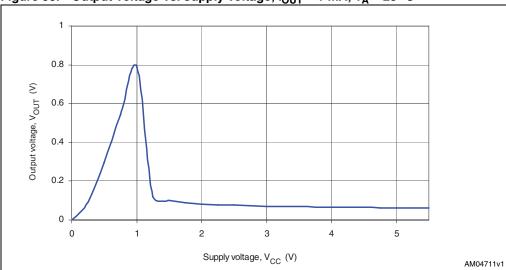


Figure 33. Output voltage vs. supply voltage, $I_{OUT} = 1$ mA, $T_A = 25$ °C

Note:

Characteristics valid for all the outputs (EN, \overline{EN} , \overline{RST} , \overline{INT} , \overline{PB}_{OUT} and \overline{VCC}_{LO}).

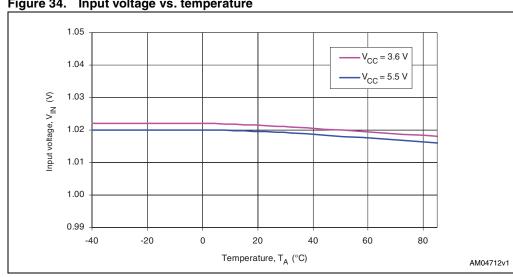


Figure 34. Input voltage vs. temperature

Note: Characteristics valid for \overline{PB} , \overline{SR} and PS_{HOLD} inputs.

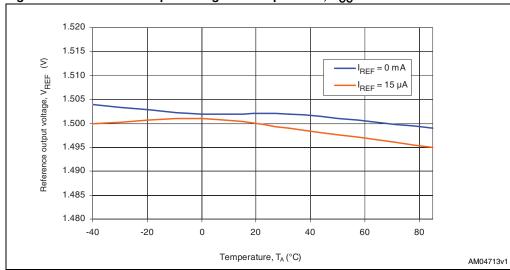


Figure 35. Reference output voltage vs. temperature, $V_{CC} = 2.0 \text{ V}$

Note: 1 μ F capacitor is connected to the V_{REF} pin.

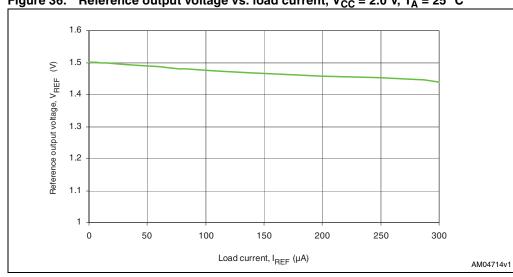


Figure 36. Reference output voltage vs. load current, V_{CC} = 2.0 V, T_A = 25 °C

Note: 1 μ F capacitor is connected to the V_{REF} pin.

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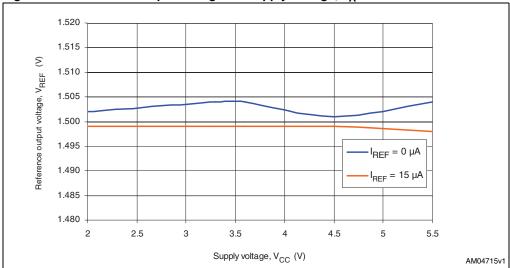


Figure 37. Reference output voltage vs. supply voltage, $T_A = 25 \, ^{\circ}\text{C}$

Note:

1 μ F capacitor is connected to the V_{REF} pin.

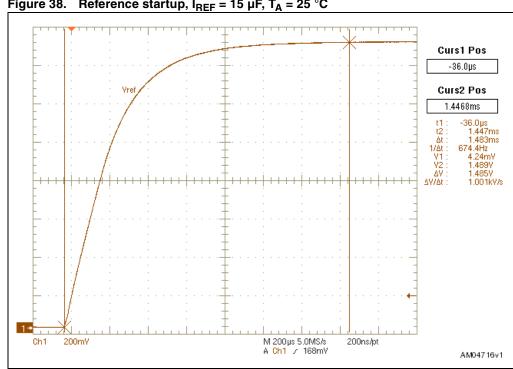


Figure 38. Reference startup, $I_{REF} = 15 \mu F$, $T_A = 25 ^{\circ}C$

Note: 1 μ F capacitor is connected to the V_{REF} pin.

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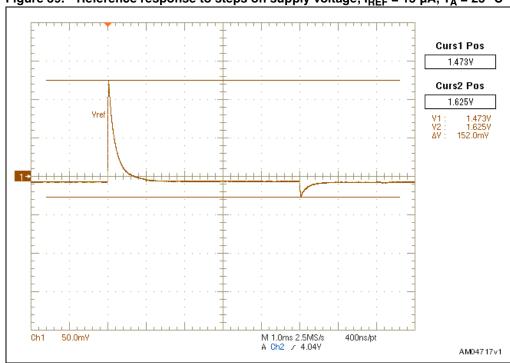


Figure 39. Reference response to steps on supply voltage, I_{REF} = 15 μ A, T_A = 25 $^{\circ}$ C

Note: 1 Supply voltage goes from 3.6 V to 5.5 V and back to 3.6 V, ramp 1 V/100 ns.

2 1 μ F capacitor is connected to the V_{REF} pin.

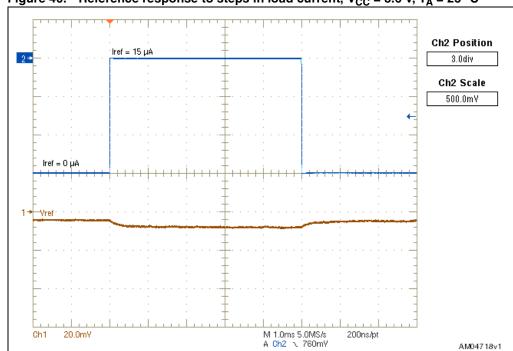


Figure 40. Reference response to steps in load current, V_{CC} = 3.6 V, T_A = 25 °C

Note: 1 Supply voltage goes from 0 μ A to 15 μ A and back to 0 μ A, ramp 1 μ A / 100 ns.

2 1 μ F capacitor is connected to the V_{REF} pin.

Maximum ratings STM6600 - STM6601

6 Maximum ratings

Stressing the device above the rating listed in the absolute maximum ratings table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 3. Absolute maximum ratings

Symbol	Parameter	Min.	Max.	Unit	Remarks
V _{CC}	Input supply voltage	-0.3	+7.0	V	
	Input voltages on \overline{PB} , \overline{SR} , PS_{HOLD} and C_{SRD}	-0.3	V _{CC} + 0.3	V	
	Output voltages on EN ($\overline{\text{EN}}$), $\overline{\text{RST}}$ and $\overline{\text{INT}}$	-0.3	V _{CC} + 0.3	٧	
V	Electrostatio protection	-2	+2	kV	Human body model (all pins)
V _{ESD}	Electrostatic protection	-8	+8	kV	Human body model (PB and SR)
V _{ESD}	Electrostatic protection	-1000	+1000	V	Charged device model
V _{ESD}	Electrostatic protection	-200	+200	٧	Machine model
V _{ESD}	Point discharge on PB and SR inputs	-8	+8	kV	IEC61000-4-2
V _{ESD}	Air discharge on PB and SR inputs	-15	+15	kV	IEC61000-4-2
T _A	Operating ambient temperature	-40	+85	°C	
T _{STG}	Storage temperature	-45	+150	°C	
T _{SLD} ⁽¹⁾	Lead solder temperature for 10 seconds		+260	°C	
θ_{JA}	Thermal resistance (junction to ambient)		+132.4	°C/W	

^{1.} Reflow at peak temperature of 260 $^{\circ}\text{C}$. The time above 255 $^{\circ}\text{C}$ must not exceed 30 seconds.

7 DC and AC characteristics

This section summarizes the operating measurement conditions and the DC and AC characteristics of the device. The parameters in the DC and AC characteristics tables that follow are derived from tests performed under the measurement conditions summarized in *Table 4*. Designers should check that the operating conditions in their circuit match the operating conditions when relying on the quoted parameters.

Table 4. Operating and AC measurement conditions

Parameter	Condition	Unit
V _{CC} supply voltage	1.6 to 5.5	V
Ambient operating temperature (T _A)	-40 to 85	°C
Input rise and fall times	≤ 5	ns

Table 5. DC and AC characteristics

Symbol	Parameter	Test condition ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
V _{CC}	Supply voltage		1.6		5.5	٧
		V _{CC} = 3.6 V, no load		6.0	8.0	μΑ
I _{CC}	Supply current	Standby mode, enable deasserted, V _{CC} = 3.6 V		0.6	1.0	μА
			2.40	2.50	2.60	
	Power-on lockout voltage		3.00	3.10	3.20	
V_{TH+}	(see Table 10 for detailed		3.20	3.30	3.40	٧
	listing)		3.29	3.40	3.51	
			3.39	3.50	3.61	
V -	Threshold hysteresis (see			200		mV
V _{HYST}	Table 10 for detailed listing)			500		IIIV
V _{TH} _	Forced power-off voltage (see <i>Table 10</i> for detailed listing)			V _{TH+} – V _{HYST}		V
t _{TH} _	Undervoltage detection to INT delay	V _{CC} ≥ 2.0 V	20	32	44	ms
	Blanking period (see		1.4	2.2	3.0	
t _{ON_BLANK}	Table 10 for detailed		5.6	8.8	12.0	s
	listing) ⁽³⁾		11.2	17.6	24.0	
	RST assertion to EN (EN) assertion delay during power-up	V _{CC} = 3.6 V		100		ns



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Table 5. DC and AC characteristics (continued)

Symbol	Parameter	Test condition ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
PB		l				<u> </u>
V _{IL}	Input low voltage	$V_{CC} \ge 2.0 \text{ V}$, enable asserted			0.99	V
V _{IH}	Input high voltage	V _{CC} ≥ 2.0 V, enable asserted	1.05			٧
t _{DEBOUNCE}	Debounce period	V _{CC} ≥ 2.0 V	20	32	44	ms
R _{PB}	Internal pull-up resistor	V _{CC} = 5.5 V, input asserted	65	100	135	kΩ
SR		,				
V _{IL}	Input low voltage				0.99	٧
V _{IH}	Input high voltage		1.05			٧
t _{DEBOUNCE}	Debounce period		20	32	44	ms
R _{SR} ⁽⁴⁾	Internal pull-up resistor	V _{CC} = 5.5 V, input asserted	65	100	135	kΩ
PB _{OUT}					•	•
V _{OL}	Output low voltage	V _{CC} = 2 V, I _{SINK} = 1 mA, PB _{OUT} asserted			0.3	V
	PB _{OUT} leakage current	V _{PBOUT} = 3 V, PB OUT open drain	-0.1		+0.1	μА
VCC _{LO}		,				
V _{OL}	Output low voltage	V _{CC} = 2 V, I _{SINK} = 1 mA, VCC _{LO} asserted			0.3	V
	VCC _{LO} leakage current	V _{VCCLO} = 3 V, VCC _{LO} open drain	-0.1		+0.1	μA
PS _{HOLD}						
V _{IL}	Input low voltage	V _{CC} ≥ 2.0 V			0.99	٧
V _{IH}	Input high voltage	V _{CC} ≥ 2.0 V	1.05			٧
	Glitch immunity		1	80		μs
	PS _{HOLD} leakage current	V _{PSHOLD} = 0.6 V	-0.1		0.1	μΑ
	PS _{HOLD} to enable propagation delay				30	μs
R _{PSHOLD}	Pull-down resistor connected internally during power-up	V _{PSHOLD} = 5.5 V	195	300	405	kΩ

Table 5. DC and AC characteristics (continued)

Symbol	Parameter	Test condition ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
C _{SRD}			<u>'</u>		<u> </u>	ı
I _{SRD}	C _{SRD} charging current		100	150	200	nA
V _{SRD}	C _{SRD} voltage threshold	V_{CC} = 3.6 V, load on V_{REF} pin 100 kΩ and mandatory 1 μF capacitor, T_A = 25 °C		1.5		V
t _{SRD}	Additional Smart Reset [™] delay time	External C _{SRD} connected		10		s/µF
EN, EN		•				
V _{OL}	Output low voltage	V _{CC} = 2 V, I _{SINK} = 1 mA, enable asserted			0.3	V
V _{OH} ⁽⁵⁾	Output high voltage	V _{CC} = 2 V, I _{SOURCE} = 1 mA, enable asserted	V _{CC} - 0.3			٧
t _{EN_OFF} ⁽⁶⁾	enable off to enable on	V _{CC} ≥ 2.0 V	40	64	88	ms
	EN, EN leakage current	V _{EN} = 2 V, enable open drain	-0.1		+0.1	μΑ
RST					1	
V _{OL}	Output low voltage	V _{CC} = 2 V, I _{SINK} = 1 mA, RST asserted			0.3	٧
t _{REC}	RST pulse width	V _{CC} ≥ 2.0 V	240	360	480	ms
	RST leakage current	V _{RST} = 3V	-0.1		+0.1	μΑ
INT					*	•
V _{OL}	Output low voltage	V _{CC} = 2 V, I _{SINK} = 1 mA, INT asserted			0.3	٧
t _{INT_Min}	Minimum INT pulse width	V _{CC} ≥ 2.0 V	20	32	44	ms
	INT leakage current	V _{INT} = 3 V	-0.1		+0.1	μΑ
V _{REF}		•			•	
V _{REF}	1.5 V voltage reference	V_{CC} = 3.6 V, load on V_{REF} pin 100 kΩ and mandatory 1 μF capacitor, T_A = 25 °C		1.5	1.515 +1%	V

- 1. Valid for ambient operating temperature: $T_A = -40$ to 85 °C; $V_{CC} = 1.6$ V to 5.5 V (except where noted).
- 2. Typical values are at T_A = +25 °C.
- 3. This blanking time allows the processor to start up correctly (see Figure 7, 8, 9, 10, 11, 12).
- 4. The internal pull-up resistor connected to the \overline{SR} input is optional (see *Table 10* for detailed device options).
- 5. Valid for push-pull only.
- 6. Minimum <u>del</u>ay time between enable deassertion and enable reassertion, allowing the application to complete the power-down properly. PB is ignored during this period.

5//

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8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of $\mathsf{ECOPACK}^{\mathbb{B}}$ packages, depending on their level of environmental compliance. $\mathsf{ECOPACK}^{\mathbb{B}}$ specifications, grade definitions and product status are available at: $\mathit{www.st.com}$. $\mathsf{ECOPACK}^{\mathbb{B}}$ is an ST trademark.

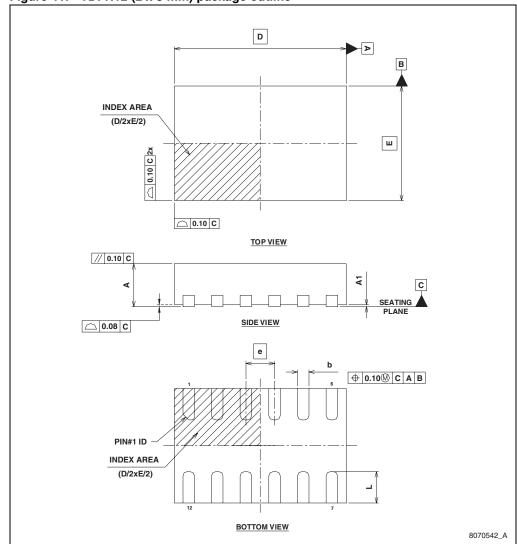


Figure 41. TDFN12 (2 x 3 mm) package outline

Table 6. TDFN12 (2 x 3 mm) package mechanical data

Symbol		mm		inches					
Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.			
Α	0.70	0.75	0.80	0.028	0.030	0.031			
A1	0.00	0.02	0.05	0.000	0.001	0.002			
b	0.15	0.20	0.25	0.006	0.008	0.010			
D		3.00 BSC			0.118				
E		2.00 BSC			0.079				
е		0.50			0.020				
L	0.45	0.55	0.65	0.018	0.022	0.026			

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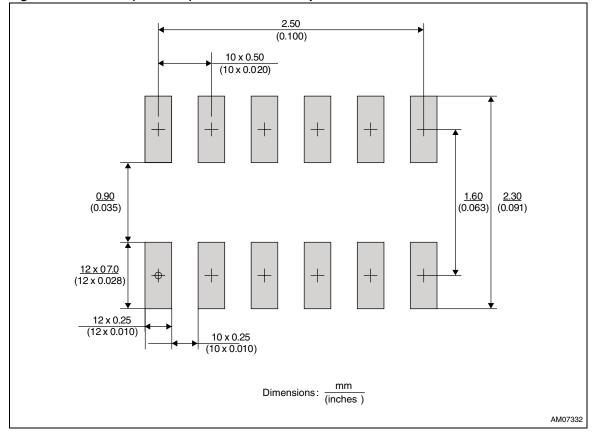


Figure 42. TDFN12 (2 x 3 mm) recommended footprint

Note: Drawing not to scale.

Figure 43. Carrier tape for TDFN12 (2 x 3 mm) package

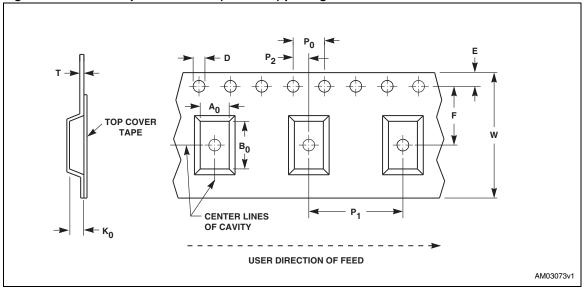
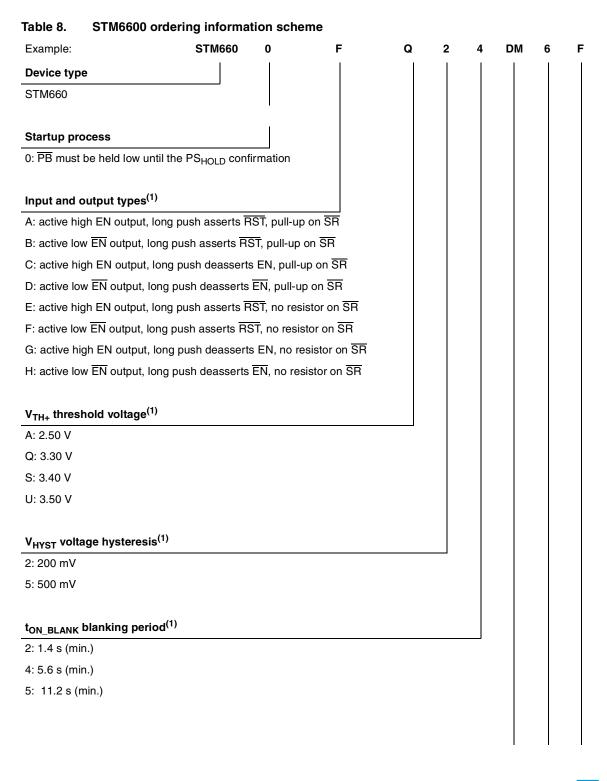


Table 7. Carrier tape dimensions for TDFN12 (2 x 3 mm) package

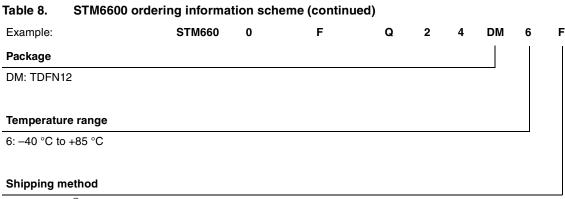
Package	W	D	E	P ₀	P ₂	F	A ₀	B ₀	K ₀	P ₁	Т	Unit	Bulk qty.
TDFN12	12.00 ±0.30	1.50 +0.10/ -0.00	1.75 ±0.10	4.00 ±0.10	2.00 ±0.10	5.50 ±0.05	2.30 ±0.10	3.20 ±0.10	1.10 ±0.01	4.00 ±0.10	0.30 ±0.05	mm	3000

Part numbering STM6600 - STM6601

9 Part numbering



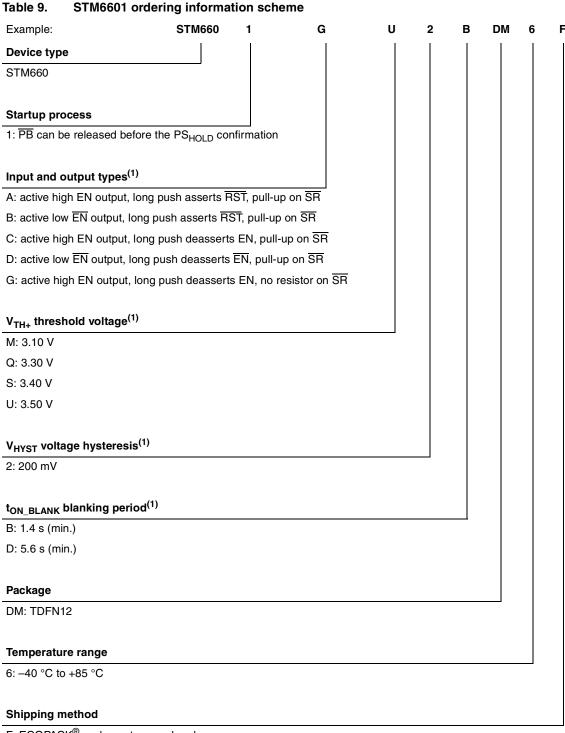
STM6600 - STM6601 Part numbering



F: ECOPACK® package, tape and reel

1. Other options are offered. Minimum order quantities may apply. Please contact local ST sales office for availability.

Part numbering STM6600 - STM6601



F: ECOPACK® package, tape and reel

1. Other options are offered. Minimum order quantities may apply. Please contact local ST sales office for availability.

STM6600 - STM6601 Product selector

10 Product selector

Table 10. STM6600 product selector

Full part number	EN or EN ⁽¹⁾	After long push ⁽²⁾	Internal resistor on SR input	Power-on lockout voltage V _{TH+} (V)	Forced power-off voltage V _{TH-} (V)	t _{ON_BLANK} (s) at startup (min.)	t _{ON_BLANK} (s) at reset (min.)	Top marking ⁽³⁾
STM6600AS24DM6F	EN	RST	pull-up	3.40	3.20	5.6	5.6	pyww AS24
STM6600BQ24DM6F	ĒΝ	RST	pull-up	3.30	3.10	5.6	5.6	pyww BQ24
STM6600CS25DM6F	EN	EN	pull-up	3.40	3.20	11.2	_	pyww CS25
STM6600DA55DM6F	ĒΝ	ĒN	pull-up	2.50	2.00	11.2	_	pyww DA55
STM6600DQ25DM6F	ĒΝ	EN	pull-up	3.30	3.10	11.2	_	pyww DQ25
STM6600DU25DM6F	ĒΝ	EN	pull-up	3.50	3.30	11.2	_	pyww DU25
STM6600ES24DM6F ⁽⁴⁾	EN	RST	_	3.40	3.20	5.6	5.6	pyww ES24
STM6600FQ24DM6F ⁽⁴⁾	ĒΝ	RST	_	3.30	3.10	5.6	5.6	pyww FQ24
STM6600GS22DM6F ⁽⁴⁾	EN	EN	_	3.40	3.20	1.4	_	pyww GS22
STM6600GS25DM6F ⁽⁴⁾	EN	EN	_	3.40	3.20	11.2	_	pyww GS25
STM6600GU22DM6F ⁽⁴⁾	EN	EN	_	3.50	3.30	1.4	_	pyww GU22
STM6600HA55DM6F ⁽⁴⁾	ĒΝ	ĒN	_	2.50	2.00	11.2	_	pyww HA55
STM6600HQ25DM6F ⁽⁴⁾	ĒΝ	EN	_	3.30	3.10	11.2	_	pyww HQ25
STM6600HU25DM6F ⁽⁴⁾	ĒΝ	EN	_	3.50	3.30	11.2	_	pyww HU25

^{1.} EN (or $\overline{\text{EN}}$) output is push-pull. $\overline{\text{RST}}$, $\overline{\text{INT}}$, $\overline{\text{PB}}_{\text{OUT}}$ and $\overline{\text{VCC}}_{\text{LO}}$ outputs are open drain.

After t_{SRD} expires through long push, either device reset (RST) will be activated for t_{REC} (240 ms min.) or the EN (or EN) pin will be deasserted. The additional Smart Reset delay time, t_{SRD}, can be adjusted by the user at 10 s/μF (typ.) by connecting the external capacitor to the C_{SRD} pin.

^{3.} Where "p" = assembly plant, "y" = assembly year (0 to 9) and "ww" = assembly work week (01 to 52).

^{4.} Please contact local ST sales office for availability.

Product selector STM6600 - STM6601

Table 11. STM6601 product selector

Full part number	EN or EN ⁽¹⁾	After long push ⁽²⁾	Internal resistor	Power-on lockout voltage V _{TH+} (V)	Forced power-off voltage V _{TH-} (V)	t _{ON_BLANK} (s) at startup (min.)	t _{ON_BLANK} (s) at reset (min.)	Top marking ⁽³⁾
STM6601AQ2BDM6F	EN	RST	pull-up	3.30	3.10	1.4	1.4	pyww AQ2B
STM6601AU2DDM6F	EN	RST	pull-up	3.50	3.30	5.6	5.6	pyww AU2D
STM6601BM2DDM6F	ĒΝ	RST	pull-up	3.10	2.90	5.6	5.6	pyww BM2D
STM6601BS2BDM6F	ĒΝ	RST	pull-up	3.40	3.20	1.4	1.4	pyww BS2B
STM6601CM2DDM6F	EN	EN	pull-up	3.10	2.90	5.6	_	pyww CM2D
STM6601CQ2BDM6F	EN	EN	pull-up	3.30	3.10	1.4	_	pyww CQ2B
STM6601CU2BDM6F	EN	EN	pull-up	3.50	3.30	1.4	_	pyww CU2B
STM6601DS2BDM6F	ĒΝ	EN	pull-up	3.40	3.20	1.4	_	pyww DS2B
STM6601GU2BDM6F ⁽⁴⁾	EN	EN	_	3.50	3.30	1.4	_	pyww GU2B

^{1.} EN (or $\overline{\text{EN}}$) output is push-pull. $\overline{\text{RST}}$, $\overline{\text{INT}}$, $\overline{\text{PB}}_{\text{OUT}}$ and $\overline{\text{VCC}}_{\text{LO}}$ outputs are open drain.

After t_{SRD} expires through long push, either device reset (RST) will be activated for t_{REC} (240 ms min.) or the EN (or EN) pin will be deasserted. The additional Smart Reset delay time, t_{SRD}, can be adjusted by the user at 10 s/μF (typ.) by connecting the external capacitor to the C_{SRD} pin.

^{3.} Where "p" = assembly plant, "y" = assembly year (0 to 9) and "ww" = assembly work week (01 to 52).

^{4.} Please contact local ST sales office for availability.

STM6600 - STM6601 Revision history

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Table 12. Document revision history

Date	Revision	Changes
04-Mar-2009	1	Initial release.
05-Jun-2009	2	Updated text in Section 2, Section 3, Figure 11, 12; updated Figure 1, 7, 9, 14, 18, 19, 43, Table 3, 5, 8, 9, 10; added Figure 8, 10, Table 7; reformatted document.
23-Jul-2009	3	Updated text in <i>Features</i> , <i>Table 1</i> , <i>8</i> , <i>9</i> , and <i>10</i> ; reformatted document.
22-Oct-2009	4	Updated Section 2, Table 5, Table 10, Figure 1, 7, 8, 9, 10, 11, 12, 14, 18, title of Section 10; added Section 5: Typical operating characteristics (Figure 23 through 40); document status upgraded to full datasheet.
25-Jan-2010	5	Updated <i>Figure 6</i> , <i>Section 2</i> , <i>Table 5</i> ; textual update to "Smart Reset [™] ".
13-Apr-2010	6	Updated Figure 1, 6, 7, 8, 9, 10, 11, 12, 13, Section 2, Section 3, Table 3, 5, 8, 9, 10.
07-Jun-2010	7	Reformatted Figure 1 and Figure 42, corrected typo in Section 3, added option A to Table 8, updated Table 10 and separated Table 10 to Table 10 and Table 11.
10-Sep-2010	8	Updated standby current to 0.6 µA throughout datasheet; removed footnote 2 of <i>Figure 14</i> ; updated <i>Table 8, 9, 11</i> ; minor textual updates.
24-Feb-2011	9	Updated Table 11 - removed footnote 4.
12-May-2011	10	Updated <i>Table 8</i> , <i>Table 10</i> and <i>Table 11</i> , minor text and typo modifications throughout document.

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